AUTOMOTIV

COMPLIANT

HALOGEN FREE



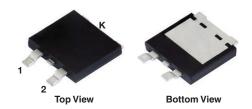
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# Vishay General Semiconductor

# Dual Low-Voltage TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.45 \text{ V}$  at  $I_F = 5.0 \text{ A}$ 

## eSMP® Series SMPD (TO-263AC)





### **LINKS TO ADDITIONAL RESOURCES**



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	60 V			
I <sub>FSM</sub>	120 A			
V <sub>F</sub> at I <sub>F</sub> = 10 A (T <sub>J</sub> = 125 °C)	0.54 V			
T <sub>J</sub> max.	175 °C			
Package	SMPD (TO-263AC)			
Circuit configuration	Common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- Very low profile typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### **MECHANICAL DATA**

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and

AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: as marked

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V20DM63C	UNIT	
Device marking code	g code		V20DM63C		
Maximum repetitive peak reverse voltage		$V_{RRM}$	60	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub> <sup>(1)</sup>	20		
	per diode		10	A	
Peak forward surge current 8.3 ms single half superimposed on rated load per diode	sine-wave	I <sub>FSM</sub>	120	А	
Operating junction temperature range		T <sub>J</sub> <sup>(2)</sup>	-40 to +175	- °C	
Storage temperature range		T <sub>STG</sub>	-55 to +175	]	

### **Notes**

- (1) Mounted on infinite heatsink
- (2) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta,IA}$



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.54	-	V
	I <sub>F</sub> = 10 A			0.60	0.66	
	I <sub>F</sub> = 5 A	T <sub>J</sub> = 125 °C		0.45	-	
	I <sub>F</sub> = 10 A			0.54	0.60	
Reverse current at rated V <sub>R</sub> per diode	V 60 V	T <sub>J</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	0.02	- mA
	$V_{R} = 60 \text{ V}$	T <sub>J</sub> = 125 °C		1.0	3.5	
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	1500	-	pF

### **Notes**

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	V20DM63C	UNIT	
Typical thermal resistance per device	R <sub>0</sub> JC <sup>(1)</sup>	1.8	°C/W	
	$R_{\theta JA}^{(2)(3)}$	58	]	

#### Notes

- (1) Mounted on infinite heatsink
- $^{(2)} \ \ \, \text{The heat generated must be less than the thermal conductivity from junction-to-ambient:} \ dP_D/dT_J < 1/R_{\theta JA} \text{junction-to-ambient}$
- (3) Free air, without heatsink

ORDERING INFORMATION (Example)						
PREFERRED P/N	ERRED P/N UNIT WEIGHT (g) PACKAGE CODE		BASE QUANTITY	DELIVERY MODE		
V20DM63C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel		
V20DM63CHM3/I (1)	0.55	l	2000/reel	13" diameter plastic tape and reel		

### Note

(1) AEC-Q101 qualified

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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

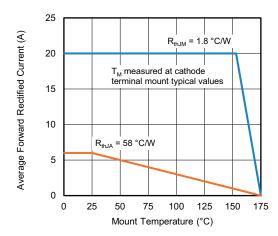


Fig. 1 - Maximum Forward Current Derating Curve

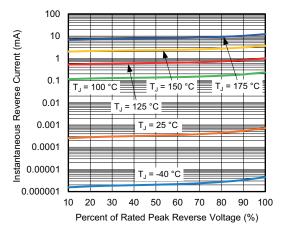


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

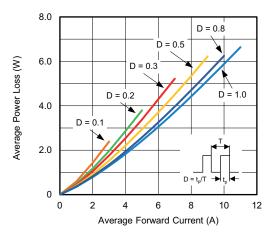


Fig. 2 - Average Power Loss Characteristics Per Diode

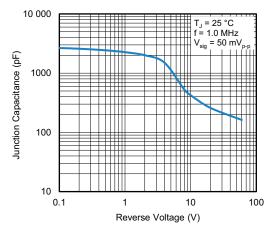


Fig. 5 - Typical Junction Capacitance Per Diode

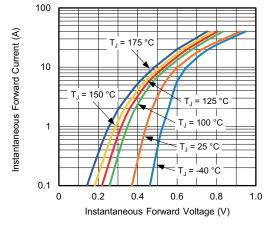


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

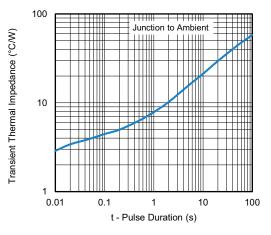


Fig. 6 - Typical Transient Thermal Impedance



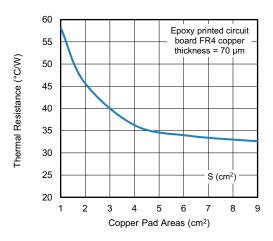
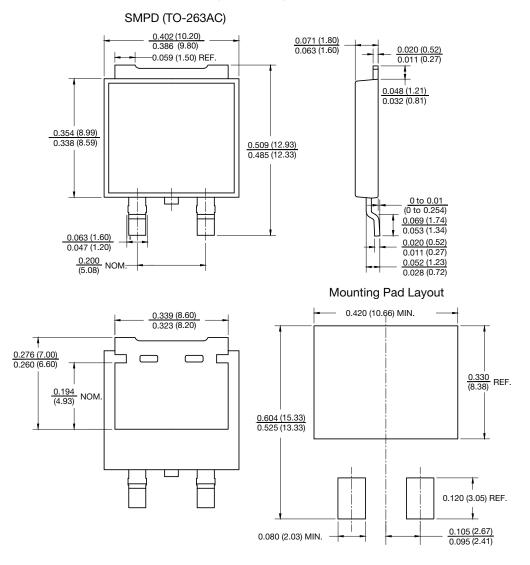


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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